

MLL-III-660D /1~1000mW

LOW NOISE RED DIODE LASER At 660nm

Low noise red diode laser 660nm is made features of ultra compact, long lifetime, low cost and easy operating, which is widely used in measurement, spectrum analysis, laser lighting show, etc.



SPECIFICATIONS

Wavelength (nm)	660 ± 5		
Output power (mW)	>1, 100, 200, ... , 1000		
Transverse mode	Multimode		
Operating mode	CW		
Power stability (rms, over 4 hours)	<1%, <3%, <5%		
Noise of amplitude (rms, 1~20MHz)	<1%		
Warm-up time (minutes)	<10		
M ² factor	<20		
Beam divergence, full angle (mrad)	<2.5		
Dimensions of beam at the aperture (mm)	~5×8		
Beam height from base plate (mm)	24. 8		
Polarization ratio	>50:1		
Operating temperature (°C)	10~35		
Power supply (90-264VAC or 5VDC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
Expected lifetime (hours)	10000		
Warranty	1 year		



MLL-III-660D	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
136(L)×73(W)×46. 2(H) mm³, 0.6kg	153 (L) ×155(W) ×92 (H) mm³, 1.5kg	133 (L) ×130(W) ×65 (H) mm³, 1.2kg	100 (L) ×62(W) ×56 (H) mm³, 0.2kg